## UNISONIC TECHNOLOGIES CO., LTD

### UTG50N120FQ-S

**Preliminary** 

Insulated Gate Bipolar Transistor

TO-247

# 1200V TRENCH GATE FIELD-STOP IGBT

#### **■** DESCRIPTION

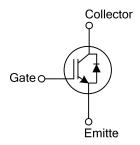
The UTC **UTG50N120FQ-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG50N120FQ-S** is suitable for the resonant or soft switching applications.

#### **■ FEATURES**

- \* High switching speed
- \* High avalanche ruggedness
- \* Low saturation voltage:  $V_{CE(SAT),Typ.}$ =1.8V @  $I_C$ =50A,  $V_{GE}$ =15V ( $T_C$  =25°C)

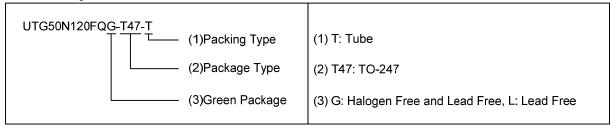
#### ■ SYMBOL



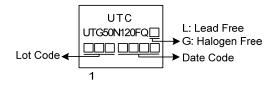
### ■ ORDERING INFORMATION

Ordering Number		Daalaaaa	Pin Assignment			Da aldin ii	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG50N120FQL-T47-T	UTG50N120FQG-T47-T	TO-247	G	С	E	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



#### ■ MARKING



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#### ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V <sub>CES</sub>	1200	V	
Gate-Emitter Voltage		.,,	±20	V	
Transient Gate-emitter voltage (tp < 5 ms)		$V_{GES}$	±25	V	
Continuous Collector Current	T <sub>C</sub> =25°C	- I <sub>C</sub>	100	Α	
	T <sub>C</sub> =100°C		50	Α	
Collector Current Pulsed (Note 1)		I <sub>CM</sub>	200	Α	
Diode Forward Current	T <sub>C</sub> =25°C	l <sub>F</sub>	60	Α	
	T <sub>C</sub> =100°C		30	Α	
Short Circuit Withstand Time $V_{\text{GE}} = 15\text{V}, \ V_{\text{CC}} \le 200\text{V}$ Allowed number of short circuits < 1000 Time between short circuits: $\ge 1.0\text{s}$ $T_{\text{VJ}} = 25^{\circ}\text{C}$		t <sub>sc</sub>		μs	
			10		
		Power Dissipation (T <sub>C</sub> =25°C)		$P_D$	285
Operating Junction Temperature		$T_J$	-40 ~ +175	°C	
Storage Temperature Range		T <sub>STG</sub>	-55 ~ +175	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

#### **■ THERMAL DATA**

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θıc	0.44	°C/W

<sup>2.</sup> Pulse width limited by maximum junction temperature.

### ■ **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS			TYP	MAX	UNIT	
Off Characteristics								
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>			1200			V	
Collector Cut-Off Current	I <sub>CES</sub>	V <sub>CE</sub> =1200V, V <sub>GE</sub> =0V				5	μΑ	
G-E Leakage Current	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V				±400	nA	
On Characteristics								
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	$I_C=250\mu A, V_{CE}=V_{GE}$		4.5		7.5	V	
Collector to Emitter Saturation Voltage		I <sub>C</sub> =50A, V <sub>GE</sub> =15V	T <sub>C</sub> =25°C		1.8	2.2	V	
	$V_{CE(SAT)}$		T <sub>C</sub> =125°C		2.2		V	
Dynamic Characteristics		_		-	-			
Input Capacitance	C <sub>IES</sub>				1960		pF	
Output Capacitance	C <sub>OES</sub>	V <sub>CE</sub> =25V, V <sub>GE</sub> =0V, f=1MHz			123.6		рF	
Reverse Transfer Capacitance	C <sub>RES</sub>			63.7		рF		
Switching Characteristics								
Total Gate Charge	$Q_G$				178.8		nC	
Gate-Emitter Charge	$Q_GE$	V <sub>CE</sub> =600V, I <sub>C</sub> =50A, V <sub>GE</sub> =15V			16.1		nC	
Gate-Collector Charge	$Q_GC$				114.6		nC	
Turn-On Delay Time	t <sub>DON)</sub>				12.9		ns	
Rise Time	t <sub>R</sub>				17.7		ns	
Turn-Off Delay Time	t <sub>DOFF)</sub>	V <sub>CC</sub> =600V, I <sub>C</sub> =50A, R <sub>G</sub> =5Ω, V <sub>GE</sub> =0~15V, L=500uH			180		ns	
Fall Time	t <sub>F</sub>				197.9		ns	
Turn-On Switching Loss	E <sub>ON</sub>				1.23		mJ	
Turn-Off Switching Loss	E <sub>OFF</sub>			1.81		mJ		
SOURCE- DRAIN DIODE RATINGS AND	CHARACTE	RISTICS						
Forward Voltage Drop	$V_{F}$	I <sub>F</sub> =50A				2.0	V	
Reverse Recovery Time	t <sub>rr</sub>	-I <sub>F</sub> =50A, dI/dt=100A/μS, V <sub>CC</sub> =400V			66.9		ns	
Reverse Recovery Charge	Q <sub>rr</sub>				3.33		uC	

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